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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SK3659

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3659 is N-channel MOS FET device that features a ounced Product low on-state resistance and excellent switching characteristics, designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

FEATURES

- •4.5V drive available.
- •Low on-state resistance,

 $R_{DS(on)1} = 5.7 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 10 \text{ V, Ip} = 40 \text{ A)}$

·Low gate charge,

 $Q_G = 32 \text{ nC TYP.}$ ($V_{DD} = 16 \text{ V}$, $V_{GS} = 10 \text{ V}$, $I_D = 65 \text{ A}$)

- •Built-in gate protection diode.
- Avalanche capability ratings.
- •Isolated TO-220 package.

ABSOLUTE MAXIMUM RATING (TA = 25°C)

		-	
Drain to source voltage (Vgs = 0 V)	Voss	20	V
Gate to source voltage (Vps = 0 V)	Vgss	±20	V
Drain current (DC) (Tc = 25°C)	ID(DC)	±65	Α
Drain current (pulse) Note1	ID(pulse)	±260	Α
Total power dissipation (T _A = 25°C)	P _{T1}	2.0	W
Total power dissipation (Tc = 25°C)	P _{T2}	25	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	35	Α
Single Avalanche Energy Note2	Eas	122	mJ

Note 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting $T_{ch} = 25^{\circ}C$, $V_{DD} = 10 \text{ V}$, $R_G = 25 \Omega$, $V_{GS} = 20 \rightarrow 0 \text{ V}$

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ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK3659	Isolated TO-220		

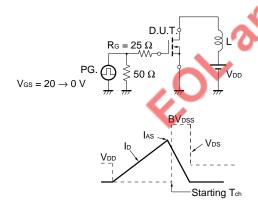


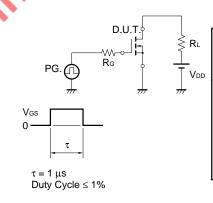
ELECTRICAL CHARACTERISTICS (TA = 25°C)

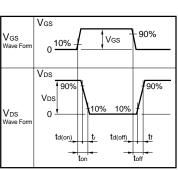
Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 20 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	lgss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5		2.5	V
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 40 A	15			S
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, ID = 40 A		4.6	5.7	mΩ
	RDS(on)2	Vgs = 4.5 V, ID = 40 A		7.1	9.9	mΩ
Input Capacitance	Ciss	Vps = 10 V		1700		pF
Output Capacitance	Coss	Vgs = 0 V		700		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		250		pF
Turn-on Delay Time	td(on)	V _{DD} = 10 V, I _D = 40 A		16		ns
Rise Time	tr	V _G s = 10 V		14		ns
Turn-off Delay Time	t _{d(off)}	$R_G = 10 \Omega$	0	50		ns
Fall Time	tr	, C		12		ns
Total Gate Charge	QG	V _{DD} = 16 V		32		nC
Gate to Source Charge	Qgs	Vgs = 10 V		6.0		nC
Gate to Drain Charge	Q _{GD}	ID = 65 A		8.3		nC
Body Diode Forward Voltage	V _{F(S-D)}	IF = 65 A, Vgs = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 65 A, VGS = 0 V		45		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		34		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

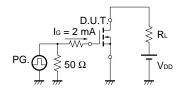
TEST CIRCUIT 2 SWITCHING TIME





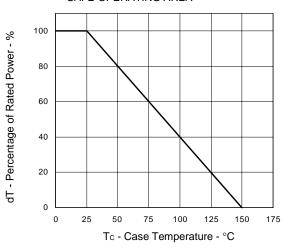


TEST CIRCUIT 3 GATE CHARGE

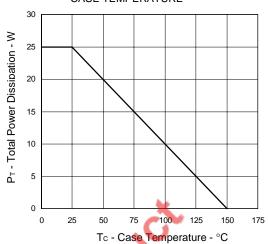


TYPICAL CHARACTERISTICS (TA = 25°C)

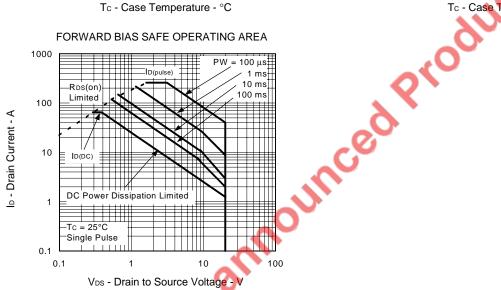
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

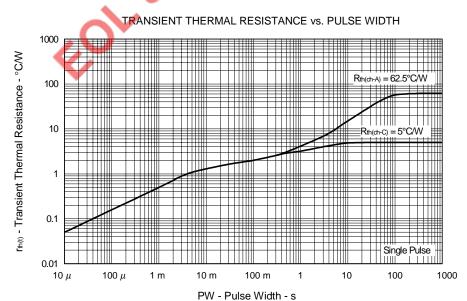


TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



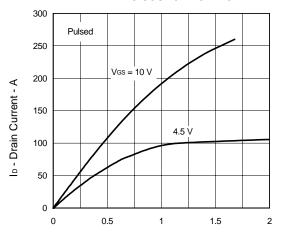
FORWARD BIAS SAFE OPERATING AREA





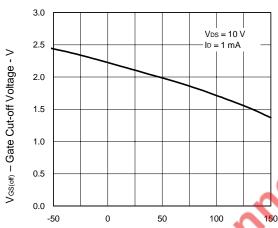
3

DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



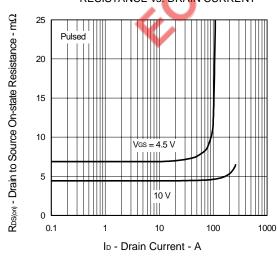
V_{DS} - Drain to Source Voltage - V

GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

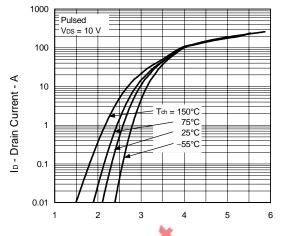


DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

Tch - Channel Temperature - °C

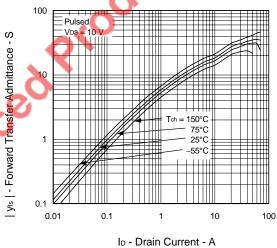


FORWARD TRANSFER CHARACTERISTICS

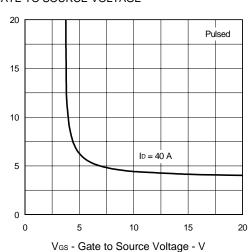


V_{GS} - Gate to Source Voltage - V

FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

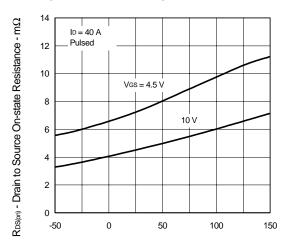


DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



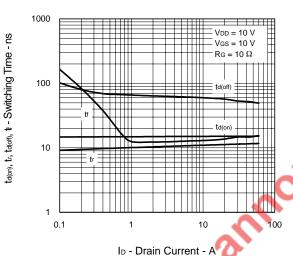
R_{DS(on)} - Drain to Source On-state Resistance - mΩ

DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

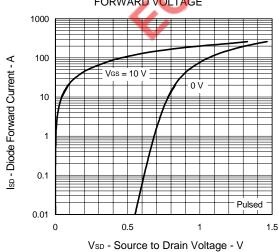


Tch - Channel Temperature - °C

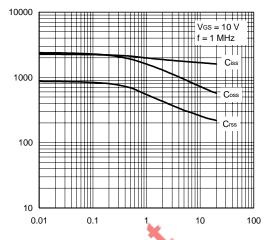
SWITCHING CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

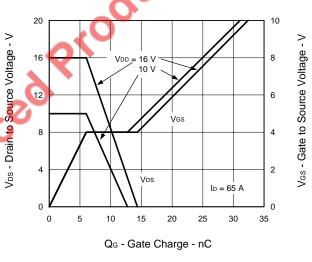


CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

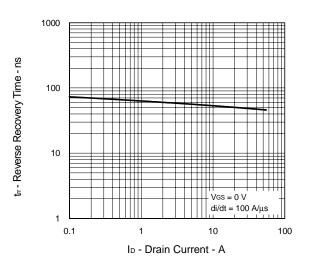


V_{DS} - Drain to Source Voltage - V

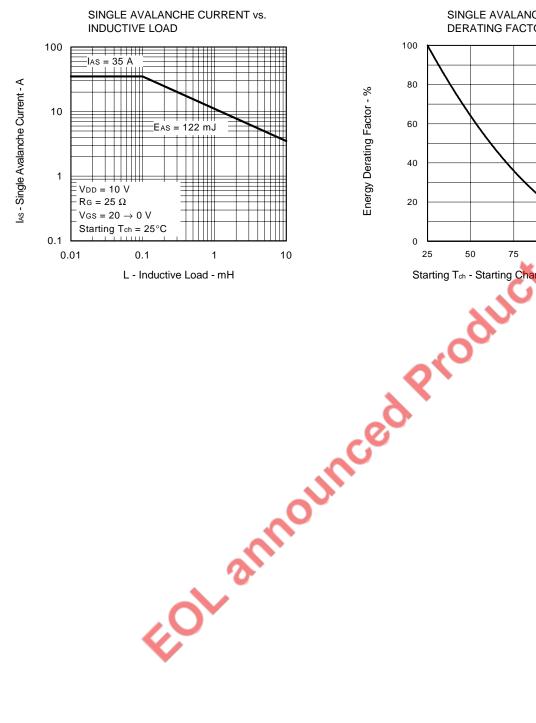
DYNAMIC INPUT/OUTPUT CHARACTERISTICS

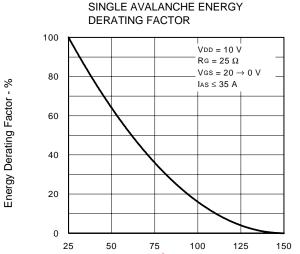


REVERSE RECOVERY TIME vs. DRAIN CURRENT



Ciss, Coss, Crss - Capacitance - pF



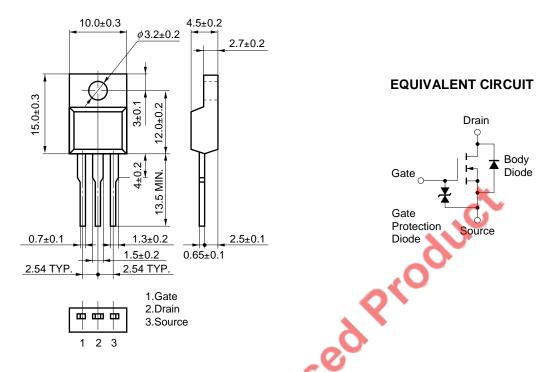


Starting Tch - Starting Channel Temperature - °C



PACKAGE DRAWING (Unit: mm)

Isolated TO-220 (MP-45F)



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

FOLan

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